

PRELIMINARY DATASHEET Cooled 1064nm Single Photon Counting Avalanche Photodiode – MMF Fiber Pigtailed PGA-308-1064

1. Product Description

The RMY SPAD is an InGaAs/InP avalanche photodetector (transferred technology from previous Princeton Lightwave Inc.) designed specifically for single photon counting applications. The device is intended for use at voltage biases above the breakdown voltage (in the so-called "Geiger mode") so that a single photon incident on the detector will give rise to a macroscopic current pulse. Optimized designed the performance in the 1064nm window, combined with appropriate pulse detection circuitry, this device allows for the detection of single photons in the wavelength range from 0.95 to 1.1µm. The RMY SPAD described in this datasheet is a back-illuminated device provided in a standard TO-8 can, 40µm diameter chip is inside. The pigtail is 62.5/125µm multi-mode optical fiber.

2. Performance Specifications

Perometer Description	Test Conditions	Specifications			11:0:4			
Parameter Description	Test conditions	Min	Тур	Max	Unit			
Linear Mode Parameters (temperature 295 K, all voltages and currents are reverse biased)								
Breakdown voltage, V _b	l _d = 10 uA 80 9		90	100	V			
Temperature dependence of V _b , γ	berature dependence of V _b , γ $\Delta V_b/\Delta T$, linear approximation		0.1		V/ºC			
Total Dark Current, Id	M=10; primarily non-multiplied Id	ultiplied Id			nA			
Capacitance, C	M=10, 1 MHz		0.4		рF			
Geiger Mode Parameters								
Detection Efficiency, DE	T=233K, 1064 nm, at DCR max 20				%			
Dark Count Rate, DCR	T=233K, 1064 nm, at DE min			10	kHz			
Afterpulse Probability(APP)	T=233K, 1064 nm, at DE min		2x10-4					

3. Maximum Ratings

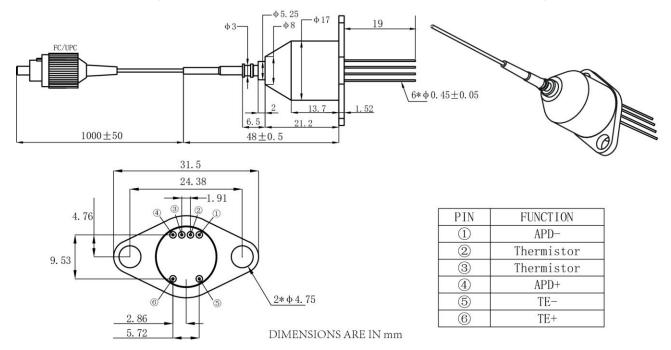
Parameter	Conditions	Min.	Max.	Units
Forward Current	Continuous bias		+1	mA
Forward Voltage	Continuous bias		+1	V
Reverse Current	Continuous bias		-1	mA
Reverse Voltage	Continuous bias		-(V _b +5)	V
Reverse Voltage	Pulsed (gated operation)		-(V _b +10)	V
Optical Power	Continuous wave (CW)		1	mW

Maximum ratings indicate conditions that the device can be exposed for short periods of time without damage. Although InGaAs SPADs are sometimes operated at temperatures below -60 °C, these devices have not yet been tested to establish their reliability characteristics at very low temperatures and under extreme conditions of thermal cycling.



4. Mechanical Specifications

The PGA-308-1064 is packaged in a standard 6 pin TO-8 header with a three stage thermo-electric cooler capable of cooling the APD from package temperature of 25°C to -50°C (223K). A multimode fiber (62.5/125µm) pigtail with an FC/PC connector is coupled to the APD. Fiber length: 1.0±0.05m



TEC SPECIFICATIONS

Parameter	Conditions	Мах	Units
TEC Current		1.5	А
TEC Voltage		1.9	V
TEC deltaT	Device case at 298K	77	°C

Thermistor = 2.20K**Ω** at 298K, 291.75K**Ω** at 223K

Steinhart-Hart Thermistor Constants: A=1.629E-03; B=2.242E-04; C=4.316E-09

5. Product Handling

These avalanche photodiodes are sensitive to electrostatic discharge (ESD) and should be handled with appropriate caution, including the use of ESD protective equipment such as grounding straps and anti-static mats.

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